

# 5A, 20V - 150V Surface Mount Schottky Barrier Rectifier

# FEATURES

- Low power loss, high efficiency
- Ideal for automated placement
- Guard ring for over-voltage protection
- High surge current capability
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

# APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- Lighting application
- Converter

# MECHANICAL DATA

- Case: DO-214AA (SMB)
- Molding compound meets UL 94V-0 flammability rating
- Moisture sensitivity level: level 1, per J-STD-020
- Packing code with suffix "G" means green compound (halogen-free)
- Part no. with suffix "H" means AEC-Q101 qualified
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 0.1 g (approximately)

KEY PARAMETERS					
PARAMETER VALUE UNIT					
I <sub>F(AV)</sub>	5	А			
V <sub>RRM</sub>	20 - 150	V			
I <sub>FSM</sub>	120 A				
Package	DO-214AA (SMB)				
Configuration	Single Die				





DO-214AA (SMB)

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)										
PARAMETER	SYMBOL	SK 52B	SK 53B	SK 54B	SK 55B	SK 56B	SK 59B	SK 510B	SK 515B	UNIT
Marking code on the device		SK 52B	SK 53B	SK 54B	SK 55B	SK 56B	SK 59B	SK 510B	SK 515B	
Repetitive peak reverse voltage	V <sub>RRM</sub>	20	30	40	50	60	90	100	150	V
Reverse voltage, total rms value	V <sub>R(RMS)</sub>	14	21	28	35	42	63	70	105	V
Maximum DC blocking voltage	V <sub>DC</sub>	20	30	40	50	60	90	100	150	V
Forward current	I <sub>F(AV)</sub>	5			Α					
Surge peak forward current, 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	120			A					
Critical rate of rise of off-state voltage	dV/dt	10000			V/µs					
Junction temperature	TJ	- 55 to +150 °			°C					
Storage temperature	T <sub>STG</sub>				- 55 to	o +150				°C





THERMAL PERFORMANCE						
PARAMETER	SYMBOL	LIMIT	UNIT			
Junction-to-lead thermal resistance	$R_{\Theta JL}$	19	°C/W			
Junction-to-ambient thermal resistance	$R_{\Theta JA}$	60	°C/W			

PARAMETER		(T <sub>A</sub> = 25°C unless oth	SYMBOL	ТҮР	MAX	UNIT
	SK52B					V
	SK53B	-		-	0.55	V
	SK54B	-				V
	SK55B		-		0.75	V
Forward voltage per diode <sup>(1)</sup>	SK56B	$I_{F} = 5A, T_{J} = 25^{\circ}C$	V <sub>F</sub>	-		V
	SK59B		-			V
	SK510B	-		-	0.85	V
	SK515B		-	-	0.95	V
	SK52B					mA
	SK53B	-				mA
	SK54B			-	0.5	mA
Reverse current @ rated V <sub>R</sub> per	SK55B					mA
diode <sup>(2)</sup>	SK56B	T <sub>J</sub> = 25°C	I <sub>R</sub>			mA
	SK59B			mA		
	SK510B	-		-	0.1	mA
	SK515B					mA
	SK52B			-	20	mA
	SK53B	-				mA
	SK54B	-	-		-	mA
Reverse current @ rated V <sub>R</sub> per	SK55B	T <sub>J</sub> = 100°C	I <sub>R</sub>			mA
diode <sup>(2)</sup>	SK56B					mA
	SK59B					mA
	SK510B	-		-		mA m A
	SK515B					mA
	SK52B			_		mA mA
	SK53B SK54B	-		-		mA mA
Reverse current @ rated V <sub>R</sub> per					mA	
diode $^{(2)}$	-	$T_{J} = 125^{\circ}C \qquad I_{R}$	I <sub>R</sub>	-	-	mA
	SK59B			-	2	mA
	SK510B					mA
	SK515B	-				mA

#### Notes:

1. Pulse test with PW=0.3 ms

2. Pulse test with PW=30 ms



ORDERING INFORMATION							
PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX(*)	PACKAGE	PACKING		
	R5		SMB	850 / 7" Plastic reel			
SK5xxB (Note 1)	н	R4	G	SMB	3,000 / 13" Paper reel		
		M4		SMB	3,000 / 13" Plastic reel		

Note:

1. "x" defines voltage from 20V (SK52B) to 150V (SK515B)

\*: Optional available

EXAMPLE P/N						
EXAMPLE P/N	PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION	
SK56BHR5G	SK56B	Н	R5	G	AEC-Q101 qualified Green compound	



## **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

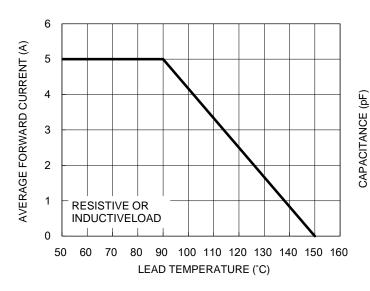
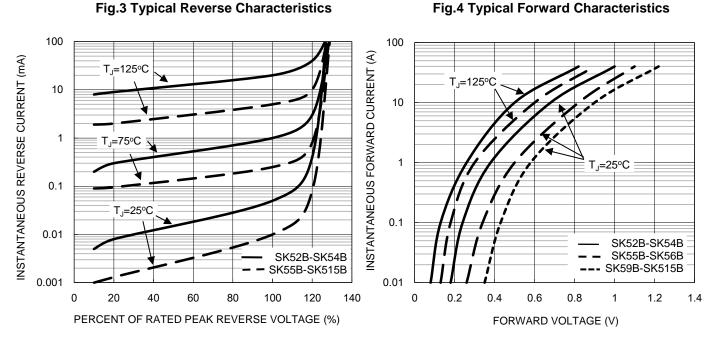


Fig.1 Forward Current Derating Curve

1000 SK52B-SK54B SK55B-SK56B 100 SK59B-SK515B f=1.0MHz Vsig=50mVp-p 1 | | | | | | | | 10 0.1 100 1 10 **REVERSE VOLTAGE (V)** 

#### **Fig.2 Typical Junction Capacitance**

**Fig.4 Typical Forward Characteristics** 

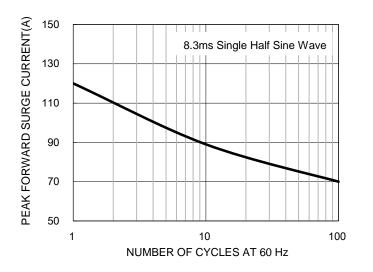


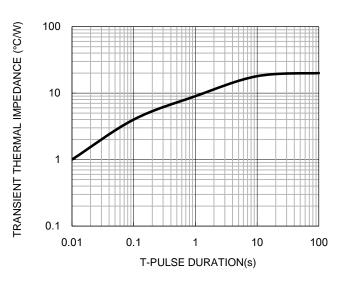


## **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

#### Fig.5 Maximum Non-repetitive Forward Surge Current





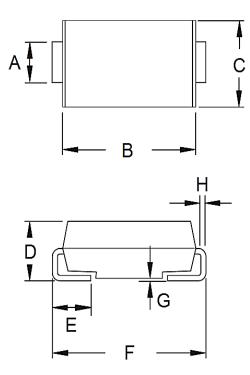
#### **Fig.6 Typical Transient Thermal Characteristics**





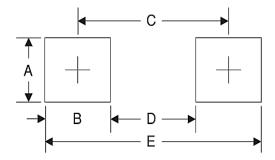
## **PACKAGE OUTLINE DIMENSIONS**

DO-214AA (SMB)



DIM.	Unit	(mm)	Unit	(inch)	
	Min	Max	Min	Max	
А	1.95	2.20	0.077	0.087	
В	4.05	4.60	0.159	0.181	
С	3.30	3.95	0.130	0.156	
D	1.95	2.65	0.077	0.104	
E	0.75	1.60	0.030	0.063	
F	5.10	5.60	0.201	0.220	
G	0.05	0.20	0.002	0.008	
н	0.15	0.31	0.006	0.012	

#### SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
A	2.3	0.091
В	2.5	0.098
С	4.3	0.169
D	1.8	0.071
E	6.8	0.268

#### **MARKING DIAGRAM**



P/N = Marking Code

- = Green Compound G
- YW = Date Code
- F = Factory Code

Version:O1705



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